





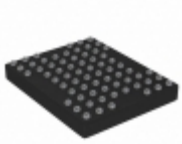
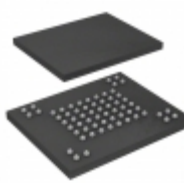




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|  <p>TOSHIBA Leading Innovation >>></p> | <h2 style="color: #e67e22;">TC58BVG0S3HTA00</h2> | |
| | <p>Hersteller-Teilenummer: TC58BVG0S3HTA00</p> <hr/> <p>Hersteller / Marke: Toshiba Semiconductor and Storage</p> <hr/> <p>Teil der Beschreibung: IC EEPROM 1GBIT 25NS 48TSOP</p> <hr/> <p>Datenblätter:  TC58BVG0S3HTA00.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 1077 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |  <p style="text-align: center; font-size: small;">YIC International Co., Limited.</p> |
| <p>Image may be representation. See specs for product details.</p> | | |

Spezifikationen

| | |
|-------------------------|---|
| Teilenummer | TC58BVG0S3HTA00 |
| Hersteller | Toshiba Semiconductor and Storage |
| Beschreibung | IC EEPROM 1GBIT 25NS 48TSOP |
| Kategorie | Integrierte Schaltungen (ICs) > Erinnerung |
| Teilstatus | 1077 pcs Stock |
| Serie | Benand™ |
| Betriebstemperatur | 0°C ~ 70°C (TA) |
| Schnittstelle | Parallel |
| Verpackung / Gehäuse | 48-TFSOP (0.724", 18.40mm Width) |
| Supplier Device-Gehäuse | 48-TSOP I |
| Spannungsversorgung | 2.7 V ~ 3.6 V |
| Speichertyp | Non-Volatile |
| Geschwindigkeit | 25ns |
| Speichergröße | 1Gb (128M x 8) |
| Speicherformat | EEPROM |
| Verpackung | Tray |



TC58BVG0S3HTA00 ist neu im Original, Suche TC58BVG0S3HTA00 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie TC58BVG0S3HTA00 Toshiba Semiconductor and Storage mit Garantie und Vertrauen. Anfrage TC58BVG0S3HTA00: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|--|--|--|---|
|  <p>TC58BVG1S3HBAI4 Toshiba Memory America, Inc. 2GB SLC BENAND 24NM BGA 9X11 (EE)</p> |  <p>TC58BVG0S3HBAI6 Toshiba Semiconductor and Storage IC EEPROM 1GBIT 25NS 67VFBGA</p> |  <p>TC58BVG0S3HBAI4 Toshiba Memory America, Inc. IC FLASH 1G PARALLEL 63TFBGA</p> |  <p>TC58BVG0S3HTAI0B4Q TOSHIBA TOSHIBA TSOP48</p> |
|  <p>TC58BVG0S3HTAI0 Toshiba Memory America, Inc. IC FLASH 1G PARALLEL 48TSOP I</p> |  <p>TC58BVG0S3HBAI4JDH TOSHIBA TOSHIBA FBGA63</p> |  <p>TC58BVG0S3HTAI0 Toshiba Semiconductor and Storage IC EEPROM 1GBIT 25NS 48TSOP</p> |  <p>TC58BVG0S3HBAI6 Toshiba Memory America, Inc. IC FLASH 1G PARALLEL 67VFBGA</p> |

heiße Teile

Mehr

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|--|--|--|---|---|
|  TC55V328AJ-15 |  TC55V328BJ-15 |  TC55V4001AFT-70L |  TC55V400FT-85 |  TC55V8128BFT-12 |
|  TC55V8128BJ-12 |  TC55V8512FT-15 |  TC55VBM316ASGN55 |  TC55VCM216ASGN55 |  TC55VCM216ASTN55 |
|  TC55VCM216ASTN55LA |  TC55VZM208AFTN12 |  TC55VZM216AFTN12LA |  TC571001D |  TC572502ECTTR |
|  TC57256AD-12 |  TC57256AD-15 |  TC57512AD-15 |  TC58128FT |  TC5816BFT |
|  TC584000F |  TC58A040F |  TC58BVG0S3HBAI6 |  TC58BVG0S3HBAI6 |  TC58BVG0S3HTA00 |
|  TC58BVG1S3HTA00 |  TC58BVG1S3HTA00 |  TC58BYG0S3HBAI4 |  TC58BYG0S3HBAI4 |  TC58BYG0S3HBAI4JDH |
|  TC58C128AFTI |  TC58C256AXB |  TC58DVG02A5TA00 |  TC58DVG14B1TG00 |  TC58DVG3S0ETA00/B4J |
|  TC58DVM72A1FT00 |  TC58DVM72A1TG00 |  TC58DVM72A1XB1 |  TC58DVM82F1TG10 |  TC58DVM82F1TG10 |
|  TC58DVM92A1FT |  TC58DVM92A2FT00 |  TC58DVM92A5TA00 |  TC58DVM92A5TAJO |  TC58DVM92F1TG10 |
|  TC58DYG02D5BAI4 |  TC58EVG0S8EBAIB |  TC58F401FT-90 |  TC58FVB160AFT-70 |  TC58FVB160FT-10 |

Contact us: Info@Y-IC.com

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